

# 1PS302

# Dual high-speed switching diode Rev. 6 — 23 July 2012

**Product data sheet** 

#### 1. **Product profile**

### 1.1 General description

Dual high-speed switching diode, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

### 1.2 Features and benefits

- High switching speed:  $t_{rr} \le 4$  ns
- Repetitive peak reverse voltage:  $V_{RRM} \le 85 V$
- Reverse voltage: V<sub>R</sub> ≤ 80 V
- AEC-Q101 qualified

- Low capacitance: C<sub>d</sub> ≤ 1.5 pF
- Repetitive peak forward current:  $I_{FRM} \leq 500~mA$
- Very small SMD plastic package

### 1.3 Applications

- High-speed switching
- General-purpose switching

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>F</sub>	forward current		[1]			
			[2] _	-	200	mA
			[3] _	-	170	mA
I <sub>R</sub>	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
$V_R$	reverse voltage		-	-	80	V
t <sub>rr</sub>	reverse recovery time		<u>[4]</u> _	-	4	ns

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



<sup>[2]</sup> Single diode loaded.

<sup>[3]</sup> Double diode loaded.

<sup>[4]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.

### **Dual high-speed switching diode**

# 2. Pinning information

Table 2. Pinning

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
1	anode		
2	cathode	3	3
3	cathode (diode 1), anode (diode 2)	1 2	
			006aaa763

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
1PS302	SC-70	plastic surface-mounted package; 3 leads	SOT323

# 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
1PS302	C*3

<sup>[1] \* =</sup> placeholder for manufacturing site code

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_{RRM}$	repetitive peak reverse voltage		-	85	V
$V_R$	reverse voltage		-	80	V
I <sub>F</sub>	forward current		<u>[1]</u>		
			[2] _	200	mA
			[3] _	170	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$	-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward	square wave	<u>[4]</u>		
	current	t <sub>p</sub> = 1 μs	-	4	А
		t <sub>p</sub> = 1 s	-	0.5	А

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#### **Dual high-speed switching diode**

 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> _	300	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	415	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	200	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V <sub>F</sub> forward voltage	forward voltage	I <sub>F</sub> = 1 mA	-	610	-	mV
	I <sub>F</sub> = 10 mA	-	740	-	mV	
		I <sub>F</sub> = 50 mA	-	-	1.0	V
		I <sub>F</sub> = 100 mA	-	-	1.2	V
I <sub>R</sub> reverse curren	reverse current	V <sub>R</sub> = 25 V	-	-	30	nA
		V <sub>R</sub> = 80 V	-	-	0.5	μΑ
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	-	-	30	μΑ
		V <sub>R</sub> = 80 V; T <sub>j</sub> = 150 °C	-	-	100	μΑ
$C_d$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	-	4	ns
$V_{FR}$	forward recovery voltage		[2] -	-	1.75	V

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.

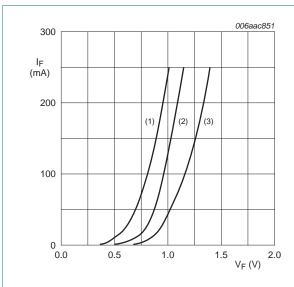
<sup>[2]</sup> Single diode loaded.

<sup>[3]</sup> Double diode loaded.

<sup>[4]</sup>  $T_j = 25$  °C before surge.

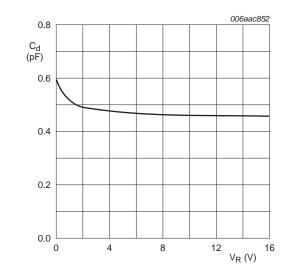
<sup>[2]</sup> When switched from  $I_F = 10$  mA;  $t_r = 20$  ns.

#### **Dual high-speed switching diode**



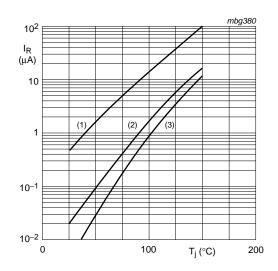
- (1)  $T_i = 150 \,^{\circ}\text{C}$ ; typical values
- (2)  $T_i = 25 \,^{\circ}C$ ; typical values
- (3)  $T_i = 25 \, ^{\circ}C$ ; maximum values

Fig 1. Forward current as a function of forward voltage



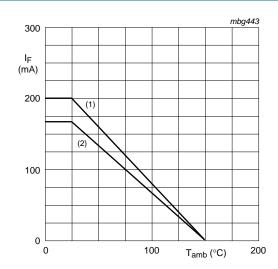
 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1)  $V_R = 80 \text{ V}$ ; maximum values
- (2) V<sub>R</sub> = 80 V; typical values
- (3)  $V_R = 25 V$ ; typical values

Fig 2. Reverse current as a function of junction temperature



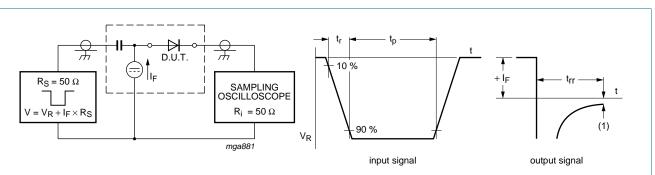
FR4 PCB, standard footprint

- (1) single diode loaded
- (2) double diode loaded

Fig 4. Forward current as a function of ambient temperature; derating curves

### **Dual high-speed switching diode**

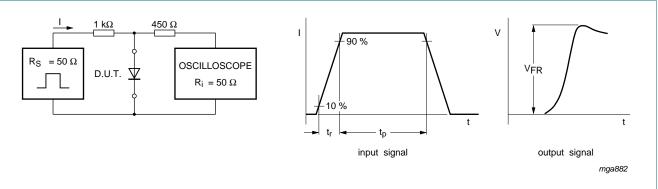
### 8. Test information



(1)  $I_R = 1 \text{ mA}$ 

Input signal: reverse pulse rise time  $t_r$  = 0.6 ns; reverse voltage pulse duration  $t_p$  = 100 ns; duty cycle  $\delta$  = 0.05 Oscilloscope: rise time  $t_r$  = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time  $t_r$  = 20 ns; forward current pulse duration  $t_p \ge 100$  ns; duty cycle  $\delta \le 0.005$ 

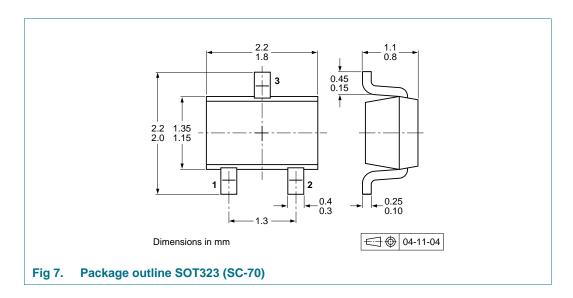
Fig 6. Forward recovery voltage test circuit and waveforms

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### **Dual high-speed switching diode**

# 9. Package outline



# 10. Packing information

Table 8. Packing methods

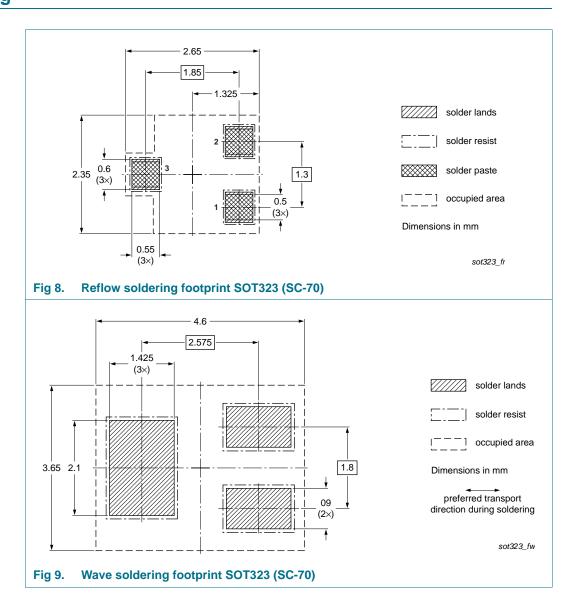
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing o	uantity
			3000	10000
1PS302	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

### **Dual high-speed switching diode**

# 11. Soldering



### Dual high-speed switching diode

# 12. Revision history

### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
1PS302 v.6	20120723	Product data sheet	-	1PS302 v.5
Modifications:	<ul> <li>Section 2 "Pi</li> </ul>	nning information": correcte	d	
1PS302 v.5	20111116	Product data sheet	-	1PS302 v.4
1PS302 v.4	19990506	Product data sheet	-	1PS302 v.3
1PS302 v.3	19961004	Product specification	-	1PS302 v.2
1PS302 v.2	19960903	Product specification	-	1PS302 v.1
1PS302 v.1	19960403	Product specification	-	-

#### **Dual high-speed switching diode**

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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